NSN 5961-00-539-1004 Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Terminal Length:
Between 0.975 inches and 1.025 inches
Overall Diameter:
Between 0.335 inches and 0.366 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
Between 0.190 inches and 0.210 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 off-state voltage, peak
Current Rating Per Characteristic:
1.00 amperes repetitive peak forward current torr
Power Rating Per Characteristic:
10.00 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0